UMW AD8541,AD8542,AD8544

1.Description

The AD8541 (single), AD8542 (dual) and AD8544 (quad) are low voltage micro power CMOS voltage feedback operational amplifiers. With an excellent bandwidth of 1.1MHz, a slew rate of 0.8V/µs, and a quiescent current of 85µA per amplifier at 5V, the AD854xA family can be designed into a wide range of applications.

The AD854x op-amps are specifically designed for general-purpose applications with optimal performance. They have a wide input common-mode voltage range and output voltage swing, and the maximum input offset voltage are 3.5mV. These parts provide rail-to-rail output swing into heavy loads. The AD854x family is specified for single or dual power supplies of +2.3V to +5.5V. All models are specified over the extended industrial temperature range of −40°C to +125°C.

The AD8541 is available in 5-lead SC70 and SOT-23 and 8-lead SOP packages. The AD8542 is available in 8-lead MSOP and SOP packages. The AD8544 is available in 14-lead TSSOP and SOP packages

2.Features

- High Gains of >100 dB for Active Filters and Gain Stages
- Low Offset Voltage: 3.5 mV Maximum with 2µV/°C Low Drift
- Gain-Bandwidth Product: 1.1 MHz
- High Slew Rate: 0.8V/µs
- Low Power: 85 µA per Amplifier Supply Current
- Settling Time to 0.1% with 2V Step: 4.5 µs
- Unit Gain Stable
- Very Low Input Bias Current: 1 pA
- Rail-to-Rail Input and Output >Input Voltage Range: -0.2V to +5.2V at 5V Supply
- Operating Power Supply: +2.3V to +5.5V
- Operating Temperature Range: -40°C to +125°C
- ESD Rating: HBM-4kV,CDM-2kV

3.Applications

- Smoke/Gas/Environment Sensors
- Audio Outputs
- Active Filters&ASIC Input or Output Amplifier
- Sensor Interfaces & Portable Equipmen

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1.1MHz, 85μA, CMOS, RRIO Operational Amplifiers

4.Pinning Information
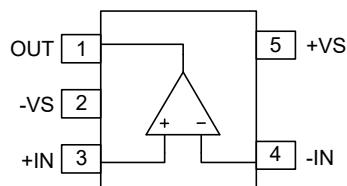
8541A

SC70-5/SOT23-5
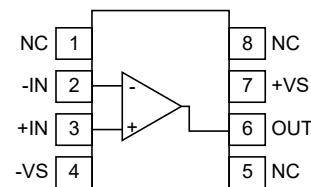
8541A

SOP-8
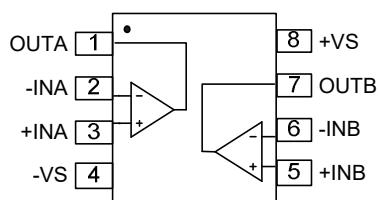
8542A

MSOP-8/SOP-8/TSSOP-8

8544A

TSSOP-14/SOP-14

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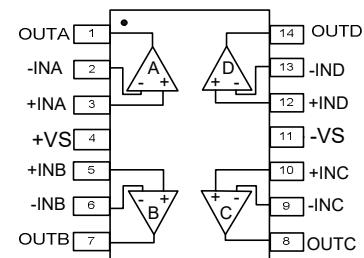
5.Pin Description

Symbol	Description
-IN	Negative (inverting) input
+IN	Positive (noninverting) input
-INA, -INB -INC, -IND	Inverting Input of the Amplifier. The voltage range can go from (V_{S-} – 0.2V) to (V_{S+} + 0.2V)
+INA, +INB +INC, +IND	Non-Inverting Input of Amplifier. This pin has the same voltage range as -IN
+V_S	Positive Power Supply. The voltage is from 2.3V to 5.5V. Split supplies are possible as long as the voltage between V_{S+} and V_{S-} is between 2.3V and 5.5V. A bypass capacitor of 0.1µF as close to the part as possible should be used between power supply pins or between supply pins and ground
-V_S	Negative Power Supply. It is normally tied to ground. It can also be tied to a voltage other than ground as long as the voltage between V_{S+} and V_{S-} is from 2.7V to 5.5V. If it is not connected to ground, bypass it with a capacitor of 0.1µF as close to the part as possible
OUTA, OUTB OUTC, OUTD	The output of the Amplifier
OUT	Output
NC	No Connection

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6.Absolute Maximum Ratings(T_A= 25°C)

Description	Symbol	Value	Units
Supply Voltage, V_{S+} to V_{S-}	V_{S+},V_{S-}	7	V
Common-Mode Input Voltage	V_{CM}	$V_{S-} - 0.4$ to $V_{S+} + 0.4$	V
Electrostatic Discharge Voltage	ESD	HBM ±4000	V
		CDM ±2000	V
Junction Temperature	T_J	160	°C
Storage Temperature Range	T_{STG}	-65 to 150	°C(T_J)
Lead Temperature Range (Soldering 10 sec)	T_{JL}	260	°C

Notes:

1. Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. Provided device does not exceed maximum junction temperature (T_J) at any time.

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7.Electrical Characteristics

V_S=5V, T_A=25°C, V_{CM}=V_S/2, V_O=V_S/2, and R_L=10kΩ connected to V_S/2, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Typ	Max	Units
INPUT CHARACTERISTICS						
Input offset voltage	V_{OS}				3.5	mV
Over temperature					4	
Offset voltage drift	$V_{OS}TC$			2		µV/°C
Input bias current	I_B			1		PA
Over temperature				500		
Input ofset current	I_{OS}			1		PA
Common-mode voltage range	V_{CM}		0		V_{S+}+0.2	V
Common-mode rejection ratio	CMRR	V_{CM}=0.05V to 5V		95		dB
Over temperature				85		
		V_{CM}=V_{S-}–0.1 to V_{S+}+0.1V		80		
Open-loop voltage gain	A_{VOL}	V_O=0.05 to 3.5 V		115		V/mV
Over temperature				100		
Input resistance	R_{IN}		100			GΩ
Input capacitance	C_{IN}	Differential		2		pF
		Common mode		3.5		
OUTPUT CHARACTERISTICS					20	
High output voltage swing	V_{OH}			4.985		V
Low output voltage swing	V_{OL}			120		mV
Closed-loop output impedance	Z_{OUT}	f=200kHz, A_V=1		50		Ω
Open-loop output impedance		f=1MHz, I_O=0		2.6		
Short-circuit current	I_{SC}	Source current through 10Ω		40		mA
		Sink current through 10Ω		40		
DYNAMIC PERFORMANCE						
Gain bandwidth product	GBW	f=1kHz		1.1		MHz
Phase margin	ΦM	C_L=100pF		60		°
Slew rate	SR	G=1,C_L=100pF, V_O=1.5V to 3.5V		0.8		V/µs

1.1MHz, 85μA, CMOS, RRIO Operational Amplifiers

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Settling time	t_S	To 0.1%, G=+1, 2V step		4.5		μs
		To 0.01%, G=+1, 2V step		5.5		
Total harmonic distortion+Noise	THD+N	f=1kHz, G=+1, V_O=3V_{PP}		0.002		%
NOISE PERFORMANCE						
Input voltage noise	V_n	f=0.1 to 10Hz		12		$μV_{P-P}$
Input voltage noise density	e_n	f=1kHz		35		nV/√Hz
Input current noise density	I_n	f=10kHz		<0.1		pA/√Hz
POWER SUPPLY						
Operating supply voltage	V_s		2.3		5.5	V
Power supply rejection ratio	PSRR	V_S=2.7V to 5.5V		105		dB
Over temperature		$V_{CM}<V_{S+}$ −2V		90		
Quiescent current (per amplifier)	I_Q			85		μA
Over temperature				90		
THERMAL CHARACTERISTICS						
Operating temperature range	T_A		-40		125	°C
Thermal resistance	$θ_{JA}$	SC70-5		333		°C/W
		SOT23-5		190		
		MSOP-8		216		
		TSSSOP-8	6	153		
		SOP-8		125		
		TSSOP-14		112		
		SOP-14		115		

Notes:

specifications subject to changes without notice

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8.1 Typical Characteristic
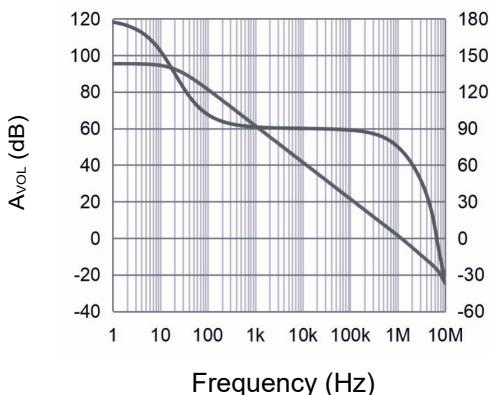
Figure 1: Open-loop Gain and Phase as a function of Frequency
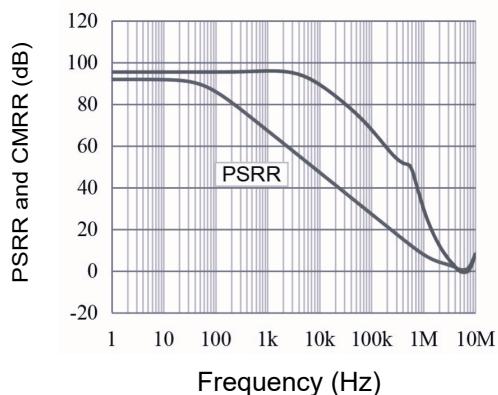
Figure 2: Power Supply and Common-mode Rejection Ratio as a function of Frequency
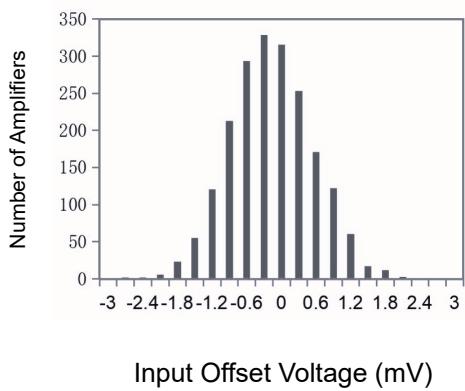
Figure 3: Input Offset Voltage Production Distribution
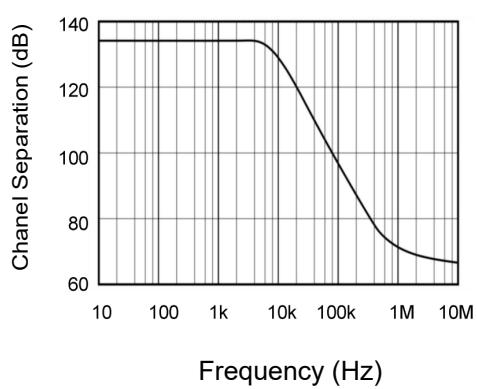
Figure 4: Channel Separation as a function of Frequency
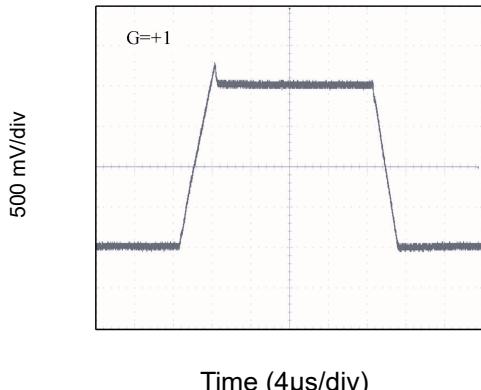
Figure 5: Large-Signal Step Response at 2.7V
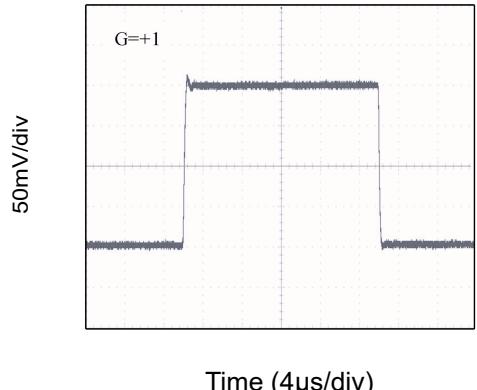
Figure 6: Small-Signal Step Response at 2.7V

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8.2Typical Characteristic
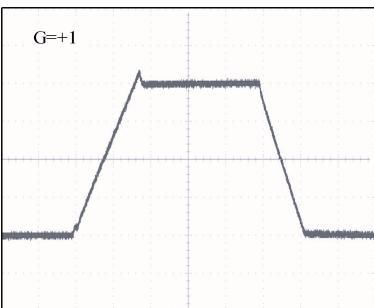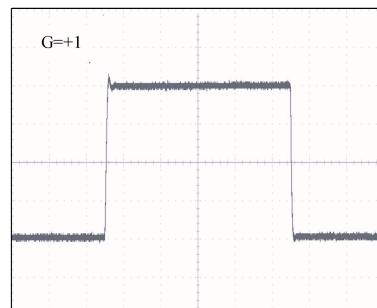
G=+1 1V/div Time (4µs/div)	G=+1 50mV/div Time (4µs/div)
Figure 7: Large-Signal Step Response at 5V	Figure 8: Small-Signal Step Response at 5V

9.Application Notes

Low Input Bias Current

The AD854x family is a CMOS op-amp family and features very low input bias current in pA range. The low input bias current allows the amplifiers to be used in applications with high resistance sources. Care must be taken to minimize PCB Surface Leakage. See below section on "PCB Surface Leakage" for more details.

Pcb Surface Leakage

In applications where low input bias current is critical, Printed Circuit Board (PCB) surface leakage effects need to be considered. Surface leakage is caused by humidity, dust or other contamination on the board. Under low humidity conditions, a typical resistance between nearby traces is 1012Ω. A 5V difference would cause 5pA of current to flow, which is greater than the AD854xA's input bias current at +25℃ (±1pA, typical). It is recommended to use multi-layer PCB layout and route the op-amp's -IN and +IN signal under the PCB surface.

The effective way to reduce surface leakage is to use a guard ring around sensitive pins (or traces). The guard ring is biased at the same voltage as the sensitive pin. An example of this type of layout is shown in Figure 1 for Inverting Gain application.

1. For Non-Inverting Gain and Unity-Gain Buffer:

a) Connect the non-inverting pin (+IN) to the input with a wire that does not touch the PCB surface.

b) Connect the guard ring to the inverting input pin (-IN). This biases the guard ring to the Common Mode input voltage.

2. For Inverting Gain and Trans-impedance Gain Amplifiers(convert current to voltage, such as photo detectors):

a) Connect the guard ring to the non-inverting input pin (+IN). This biases the guard ring to the same reference voltage as the op-amp (e.g., VS/2 or ground).

b) Connect the inverting pin (-IN) to the input with a wire that does not touch the PCB surface.
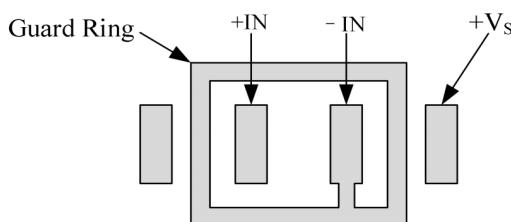
Figure 1. Use a guard ring around sensitive pins

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Ground Sensing And Rail To Rail

TThe input common-mode voltage range of the AD854xA series extends 200mV beyond the supply rails. This is achieved with a complementary input stage—an N-channel input differential pair in parallel with a P-channel differential pair. For normal operation, inputs should be limited to this range. The absolute maximum input voltage is 400mV beyond the supplies. Inputs greater than the input common-mode range but less than the maximum input voltage, while not valid, will not cause any damage to the op-amp. Unlike some other opamps, if input current is limited, the inputs may go beyond the supplies without phase inversion, as shown in Figure 2. Since the input common-mode range extends from (V_{S-} −0.2V) to (V_{S+} + 0.2V), the AD854xA op-amps can easily perform 'true ground' sensing
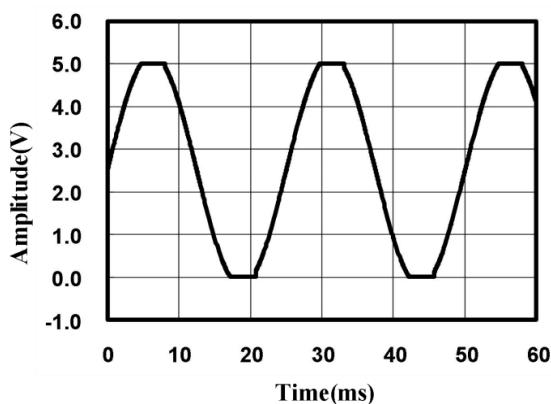
Figure 2. No Phase Inversion with Inputs Greater Than the Power-Supply Voltage

A topology of class AB output stage with common-source transistors is used to achieve rail-to-rail output. For light resistive loads (e.g.100kΩ), the output voltage can typically swing to within 5mV from the supply rails. With moderate resistive loads (e.g.10kΩ), the output can typically swing to within 10mV from the supply rails and maintain high open-loop gain.

The maximum output current is a function of total supply voltage. As the supply voltage to the amplifier increases, the output current capability also increases. Attention must be paid to keep the junction temperature of the IC below 150°C when the output is in continuous short-circuit. The output of the amplifier has reverse-biased ESD diodes connected to each supply. The output should not be forced more than 0.5V beyond either supply, otherwise current will flow through these diodes.

Capacitive Load And Stability

The AD854xA can directly drive 1nF in unity-gain without oscillation. The unity-gain follower is the most sensitive configuration to capacitive loading. Direct capacitive loading reduces the phase margin of amplifiers and this results in ringing or capacitive loading reduces the phase margin of amplifiers and this results in ringing or even oscillation. Applications that require greater capacitive drive capability should use an isolation resistor between the output and the capacitive load like the circuit in Figure 3. The isolation resistor R_{ISO} and the load capacitor C_L form a zero to increase stability. The bigger the R_{ISO} resistor value, the more stable VOUT will be. Note that this method results in a loss of gain accuracy because R_{ISO} forms a voltage divider with the R_L.
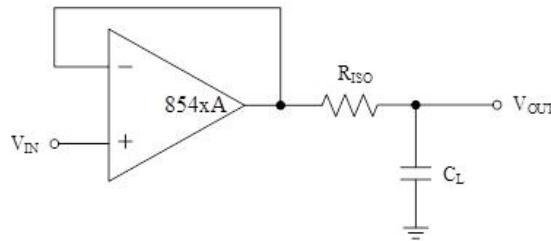
Figure 3. Indirectly Driving Heavy Capacitive Load

An improvement circuit is shown in Figure 4. It provides DC accuracy as well as AC stability. The RF provides the DC accuracy by connecting the inverting signal with the output. The C_F and R_{ISO} serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving phase margin in the overall feedback loop.
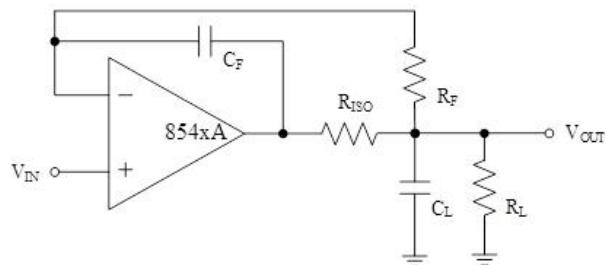
Figure 4. Indirectly Driving Heavy Capacitive Load with DC Accuracy

For no-buffer configuration, there are two other ways to increase the phase margin: (a) by increasing the amplifier's gain, or (b) by placing a capacitor in parallel with the feedback resistor to counteract the parasitic capacitance associated with inverting node.

Power Supply La 4out And By ass

The AD854xA family operates from either a single +2.3V to +5.5V supply or dual ±1.15V to ±2.75V supplies. For single-supply operation, bypass the power supply V_S with a ceramic capacitor (i.e. 0.01µF to 0.1µF) which should be placed close (within 2mm for good high frequency performance) to the VS pin. For dual-supply operation, both the V_{S+} and the V_{S-} supplies should be bypassed to ground with separate 0.1µF ceramic capacitors. A bulk capacitor (i.e. 2.2µF or larger tantalum capacitor) within 100mm to provide large, slow currents and better performance. This bulk capacitor can be shared with other analog parts. Good PC board layout techniques optimize performance by decreasing the amount of stray capacitance at the op-amp's inputs and output. To decrease stray capacitance, minimize trace lengths and widths by placing external components as close to the device as possible. Use surface-mount components whenever possible. For the op-amp, soldering the part to the board directly is strongly recommended. Try to keep the high frequency big current loop area small to minimize the EMI (electromagnetic interfacing).

Grounding

A ground plane layer is important for the AD854xA circuit design. The length of the current path speed currents in an inductive ground return will create an unwanted voltage noise. Broad ground plane areas will reduce the parasitic inductance.

Input-to-output Coupling

To minimize capacitive coupling, the input and output signal traces should not be parallel.This helps reduce unwanted positive feedback.

10.Typical Application Circuits

Differential Amplifier
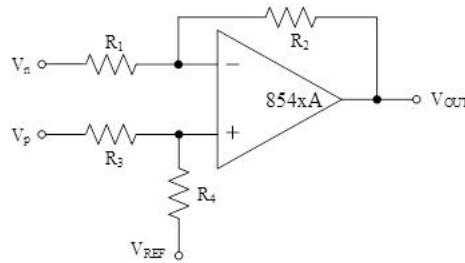
Figure 5. Differential Amplifier

The circuit shown in Figure 5 performs the difference function. If the resistors ratios are equal $R_4/R_3 = R_2/R_1$, then:

$$V_{OUT}=(V_p - V_n) \times R_2/R_1 + V_{REF}$$

Instrumentation Amplifier
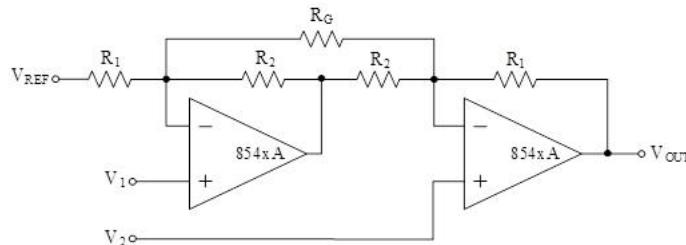
$$V_{OUT}=(V_1 - V_2) \times (1+ R_1/R_2 + 2R_1/R_G) + V_{REF}$$

Figure 6. Instrumentation Amplifier

The AD854xA family is well suited for conditioning sensor signals in battery-powered applications. Figure 6 shows a two op-amp instrumentation amplifier, using the AD854xA op-amps. The circuit works well for applications requiring rejection of common-mode noise at higher gains. The reference voltage (V_{REF}) is supplied by a low-impedance source. In single voltage supply applications, the V_{REF} is typically $V_S/2$.

Buffered Chemical Sensors
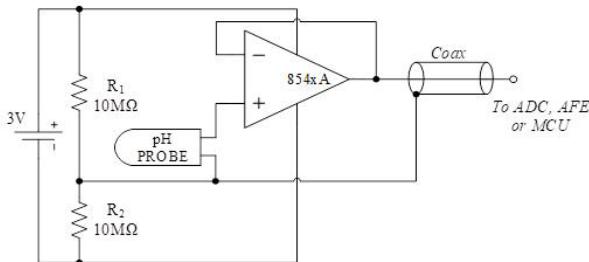
Figure 7. Buffered pH Probe

The AD854xA family has input bias current in the pA range. This is ideal in buffering high impedance chemical sensors, such as pH probes. As an example, the circuit in Figure 7 eliminates expansive low-leakage cables that that is required to connect a pH probe (general purpose combination pH probes, e.g. Corning 476540) to metering ICs such as ADC, AFE and/or MCU. An AD854xA op-amp and a lithium battery are housed in the probe assembly. A conventional low-cost coaxial cable can be used to carry the op-amp's output signal to subsequent ICs for pH reading.

Shunt-based Current Sensing Amplifier

The current sensing amplification shown in Figure 8 has a slew rate of $2\pi f V_{PP}$ for the output of sine wave signal, and has a slew rate of $2fV_{PP}$ for the output of triangular wave signal. In most of motor control systems, the PWM frequency is at 10kHz to 20kHz, and one cycle time is 100μs for a 10kHz of PWM frequency. In current shunt monitoring for a motor phase, the phase current is converted to a phase voltage signal for ADC sampling. This sampling voltage signal must be settled before entering the ADC. As the Figure 8 shown, the total settling time of a current shunt monitor circuit includes: the rising edge delay time (t_{SR}) due to the op-amp's slew rate, and the measurement settling time (t_{SET}). For a 3-shunt solution in motor phase current sensing, if the smaller duty cycle of the PWM is defined at 45% (In fact, the phase with minimum PWM duty cycle, such as 5%, is not detected current directly, and it can be calculated from the other two phase currents), and the tSR is required at 20% of a total time window for a phase current monitoring, in case of a 3.3V motor control system

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(3.3V MCU with 12-bit ADC), the op-amp's slew rate should be more than:

$$3.3V/(100µs × 45\% × 20\%) = 0.37 \text{ V/µs}$$

At the same time, the op-amp's bandwidth should be much greater than the PWM frequency, like 10 time at least.
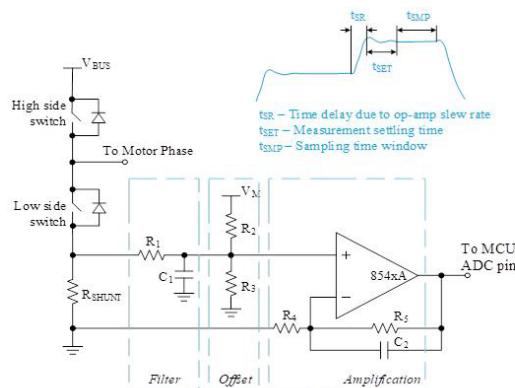
Figure 8. Current Shunt Monitor Circuit

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11.1 SC70-5 Package Outline Dimensions
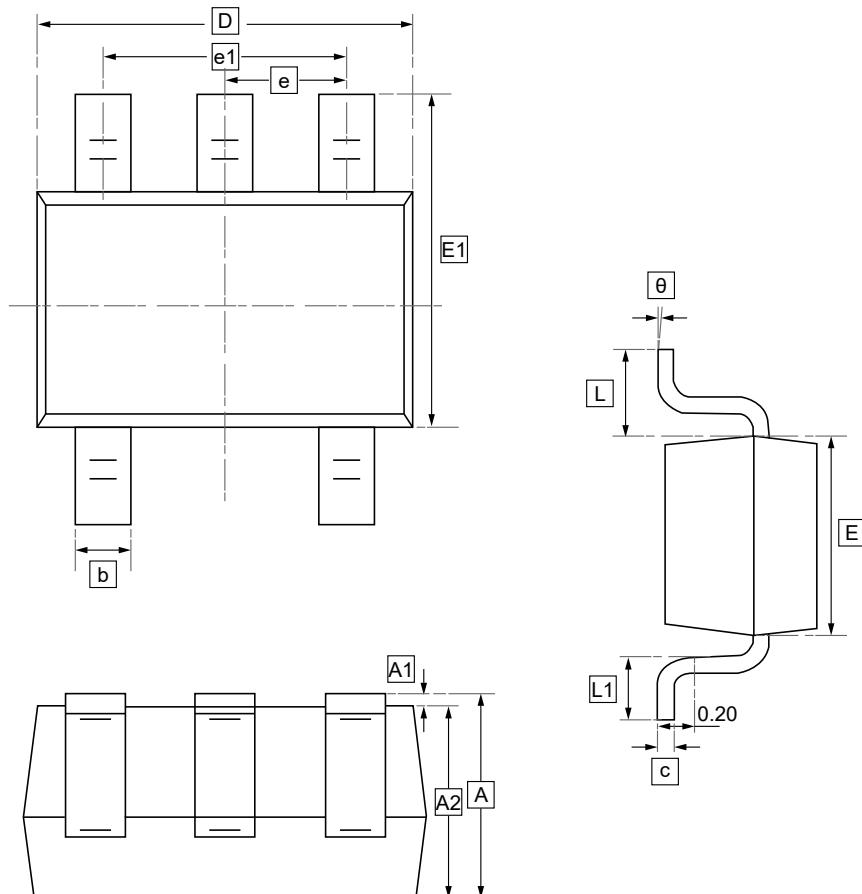
DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A2	b	c	D	E	E1	e	e1	L	θ
Min	0.90	0.00	0.90	0.15	0.08	2.05	1.15	2.15	0.65	1.20	0.26	7°
Max	1.10	0.10	1.00	0.35	0.15	2.25	1.35	2.45	TYP	1.40	0.46	REF.

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11.2 SOT23-5 Package Outline Dimensions
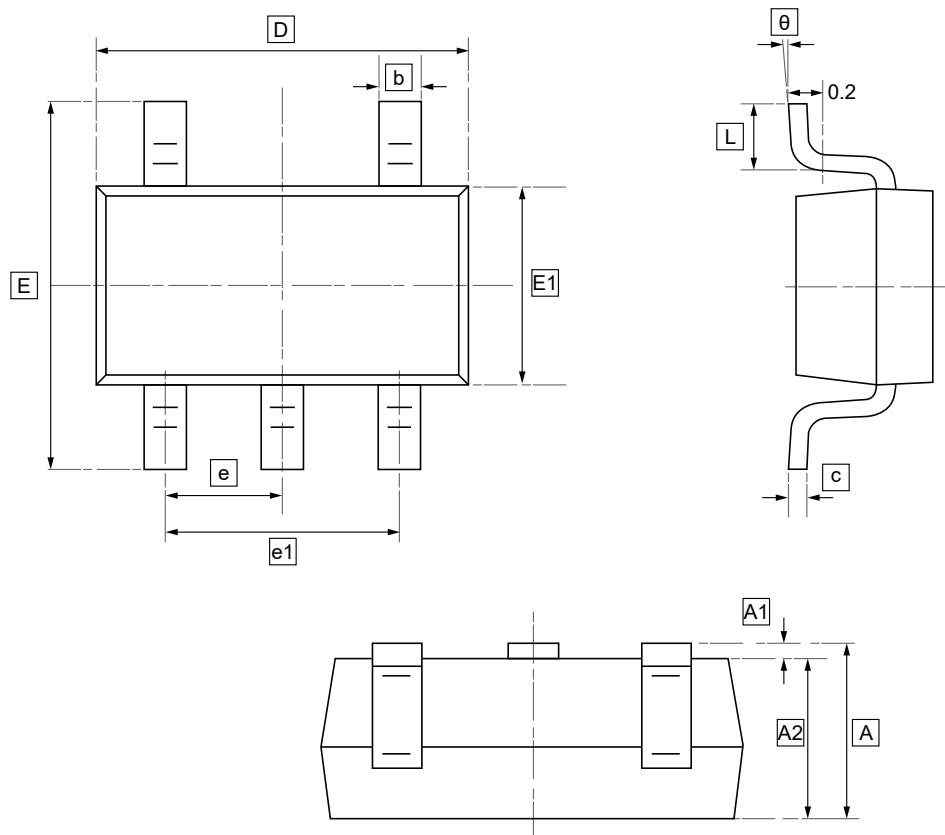
DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A2	b	c	D	E1	E	e	e1	L	θ
Min	1.050	0.000	1.050	0.300	0.100	2.820	1.500	2.650	0.950	1.800	0.300	0°
Max	1.250	0.100	1.150	0.500	0.200	3.020	1.700	2.950	BSC	2.000	0.600	8°

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11.3 MSOP-8 Package Outline Dimensions
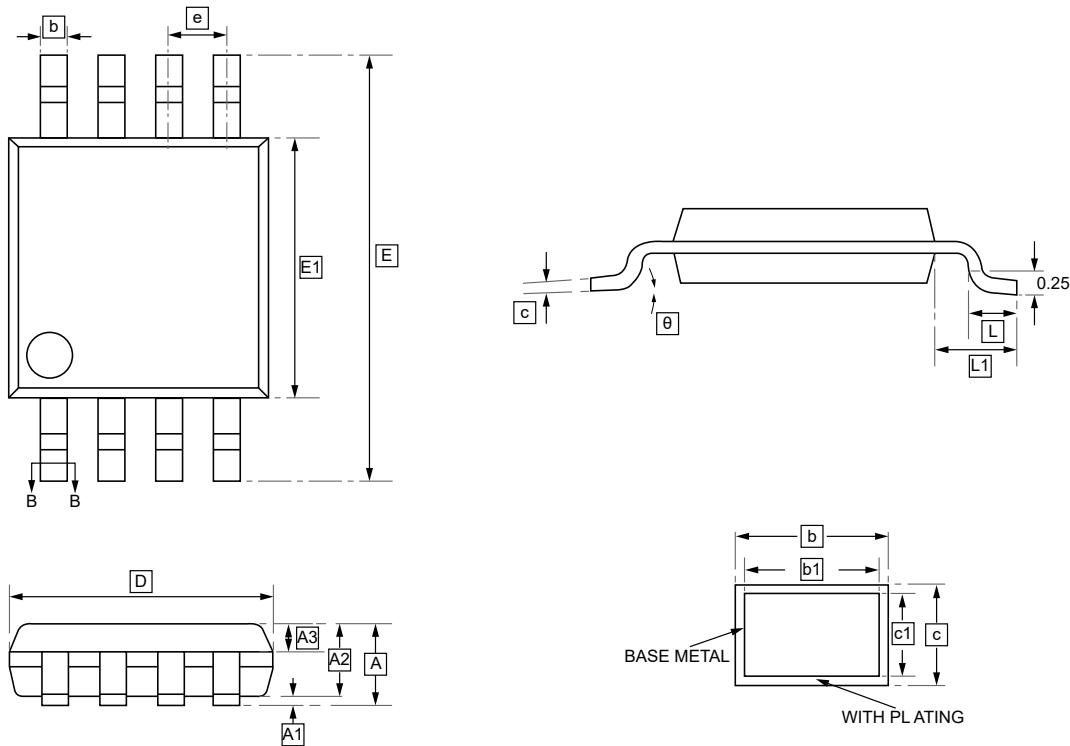
DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A2	A3	b	b1	c	c1	D	E	E1	e
Min	-	0.05	0.75	0.30	0.28	0.27	0.15	0.14	2.90	4.70	2.90	0.65
Max	1.10	0.15	0.95	0.40	0.36	0.33	0.19	0.16	3.10	5.10	3.10	BSC

Symbol	L	L1	θ
Min	0.40	0.95	0°
Max	0.70	REF	8°

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11.4 SOP-8 Package Outline Dimensions
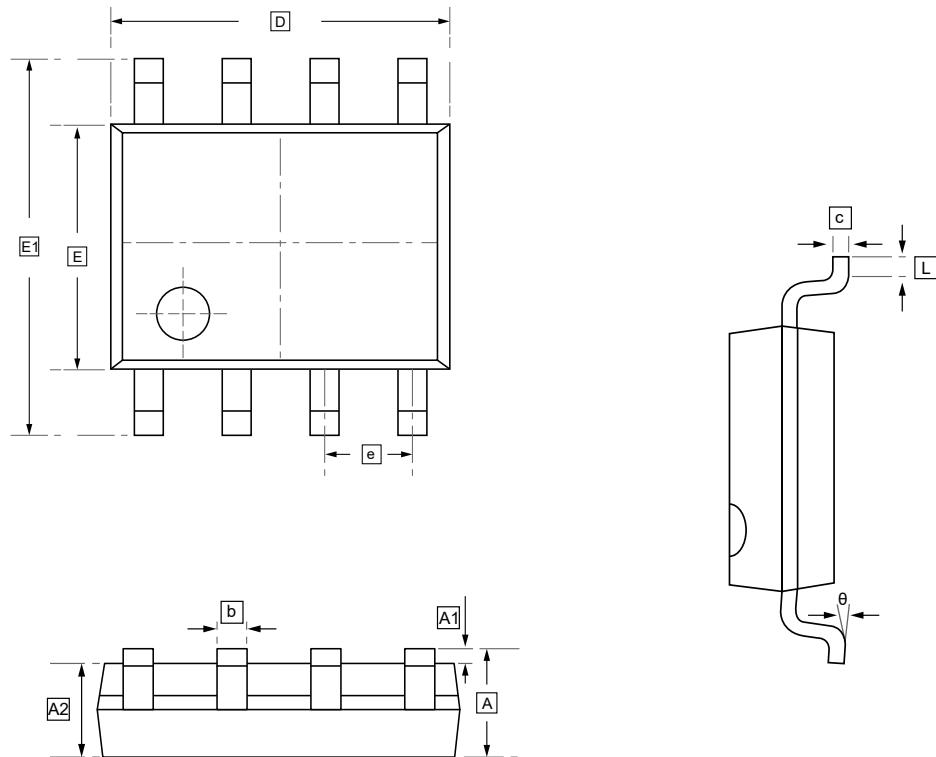
DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A2	b	c	D	E	E1	e	L	θ
Min	1.350	0.000	1.350	0.330	0.170	4.700	3.800	5.800	1.270	0.400	0°
Max	1.750	0.100	1.550	0.510	0.250	5.100	4.000	6.200	BSC	1.270	8°

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11.5 TSSOP-8 Package Outline Dimensions
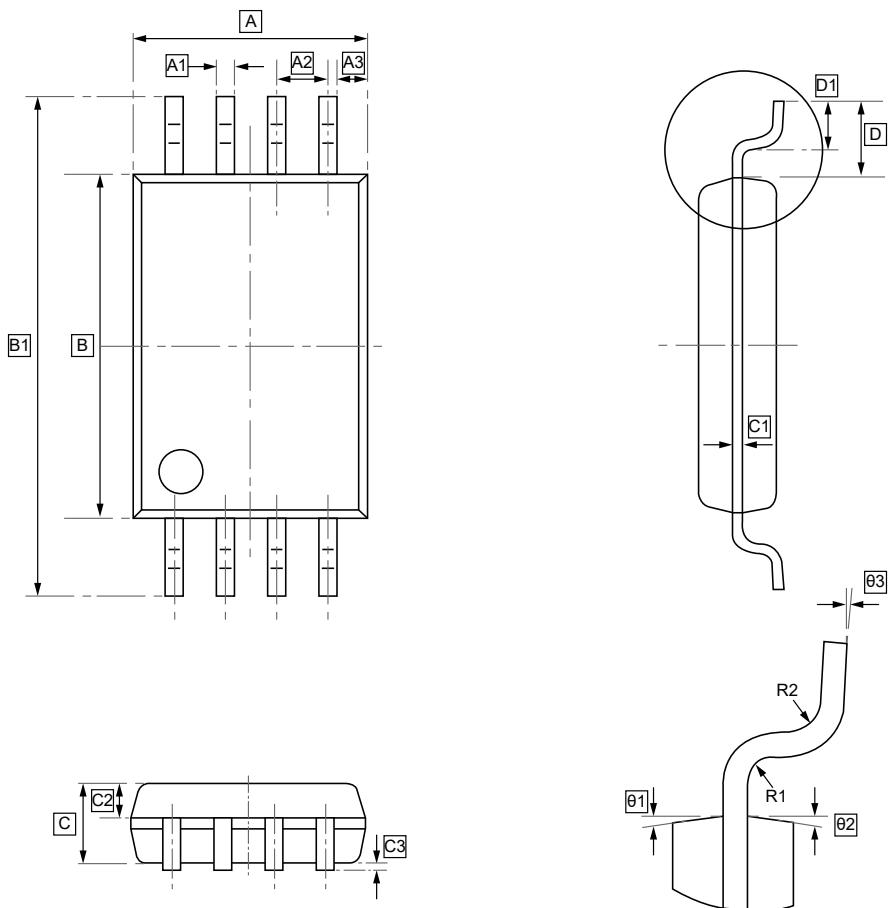
DIMENSONS (mm are the original dimensions)

Symbol	A	A1	A2	A3	B	B1	C	C1	C2	C3	D	D1
Min	2.90	0.20	0.65	0.36	4.30	6.30	0.95	0.127	0.39	0.05	1.00	0.50
Max	3.10	0.30	TYP	0.46	4.50	6.50	1.05	TYP	0.49	0.15	REF	0.70

Symbol	R1	R2	θ1	θ2	θ3
Min	0.15	0.15	12°	12°	0°
Max	TYP	TYP	TYP4	TYP4	7°

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11.6 SOP-14 Package Outline Dimensions
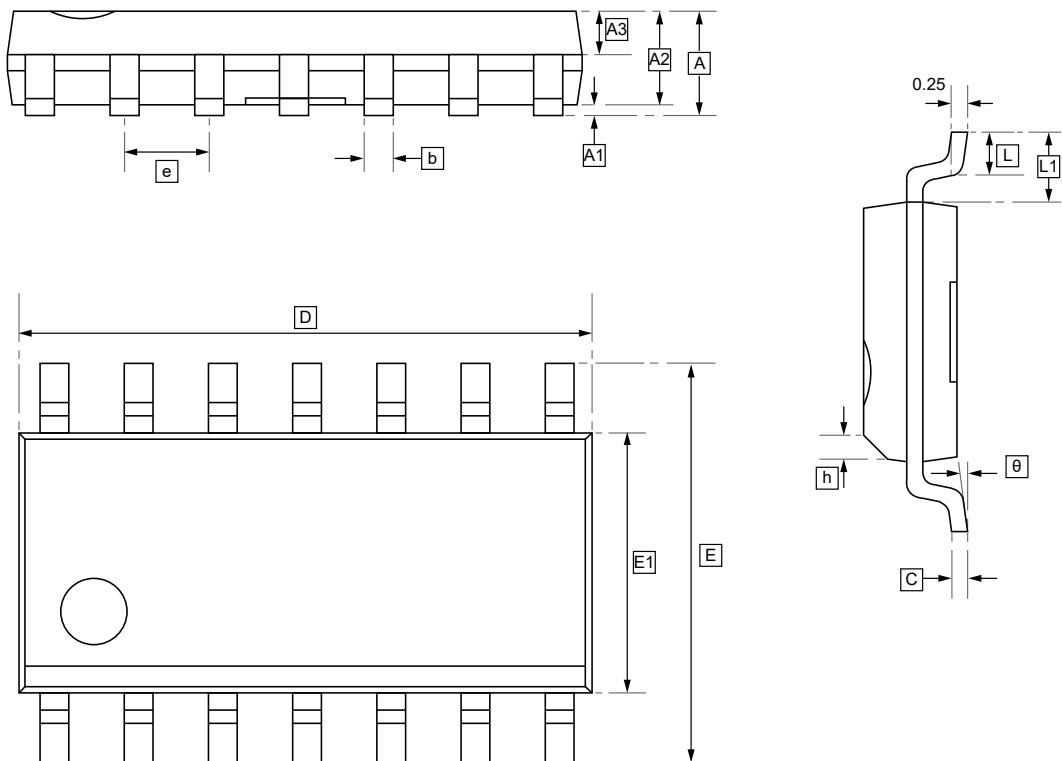
DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A2	A3	b	C	D	E	E1	e	h	L
Min	-	0.05	1.35	0.65	0.203	0.17	8.45	5.80	3.80	1.24	0.25	0.40
Max	1.75	0.25	1.55	0.75	0.305	0.25	8.85	6.20	4.00	1.30	0.50	0.80

Symbol	L1	θ
Min	1.00	0°
Max	1.10	8°

11.7 TSSOP-14 Package Outline Dimensions
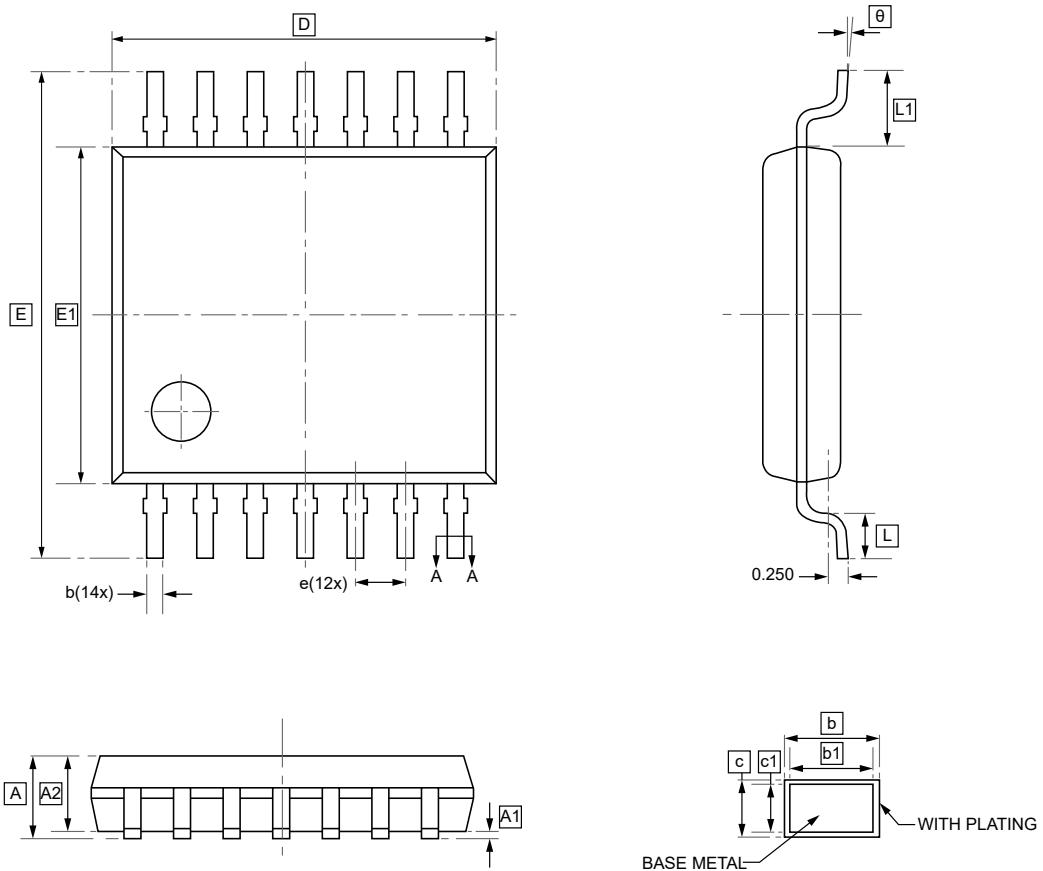
DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A2	b	b1	c	c1	D	E	E1	e	L1
Min	-	0.05	0.90	0.20	0.19	0.13	0.120	4.90	6.20	4.30	0.65	0.85
Max	1.20	0.15	1.05	0.28	0.25	0.17	0.14	5.10	6.60	4.50	BSC	1.15

Symbol	L	θ
Min	0.45	0°
Max	0.75	8°

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Apr.2025

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12.Ordering information

SOT23-5

A4A

UMW yww

TSSOP-8

AD8542
UMW yww
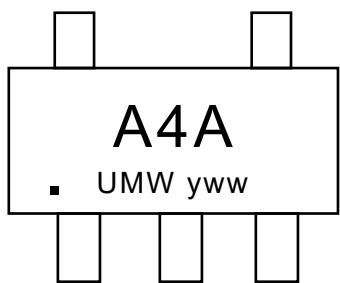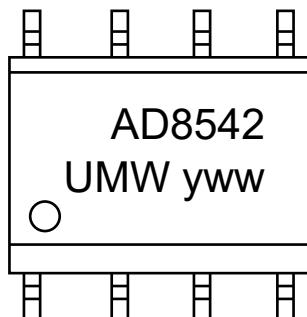
TSSOP-14
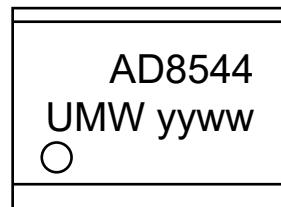
AD8544
UMW yyww

yy: Year Code
ww: Week Code

Order Code	Marking	Package	Base QTY	Delivery Mode
UMW AD8541ARZ	AD8541	SOP-8	2500	Tape and reel
UMW AD8542ARMZ	AD8542	MSOP-8	2500	Tape and reel
UMW AD8542ARZ	AD8542	SOP-8	2500	Tape and reel
UMW AD8544ARUZ	AD8544	TSSOP-14	2500	Tape and reel
UMW AD8544ARZ	AD8544	SOP-14	2500	Tape and reel
UMW AD8541AKSZ	A12	SC70-5	3000	Tape and reel
UMW AD8541ARTZ	A4A	SOT23-5	3000	Tape and reel
UMW AD8542ARUZ	AD8542	TSSOP-8	4000	Tape and reel

13.Disclaimer

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